



Docket No.: T2171.0214

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Tomoyasu Aoshima

Application No.: 10/773,244

Confirmation No.: 7164

Filed: February 9, 2004

Art Unit: 1763

For: ANISOTROPIC WET ETCHING OF

SILICON

Examiner: Not Yet Assigned

REQUEST FOR CORRECTED FILING RECEIPT

Filing Receipt Corrections
Office of Initial Patent Examination
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Applicant hereby requests that a corrected Filing Receipt be issued in the aboveidentified patent application. The official Filing Receipt received by Applicant, a copy of which is attached hereto, has an error in the date of the Foreign Application.

Please correct the date of the Foreign Application to read: 02/10/2003.

A copy of the certified priority document is enclosed for reference.

Applicant additionally requests that all pertinent U.S. Patent and Trademark Office records relating to the subject application be changed to reflect this correction.

Application No.: 10/773,244 Docket No.: T2171.0214

Dated: June 14, 2004

Respectfully submitted,

Michael J. Scheer

Registration No.: 34,425

DICKSTEIN SHAPIRO MORIN &

OSHINSKY LLP

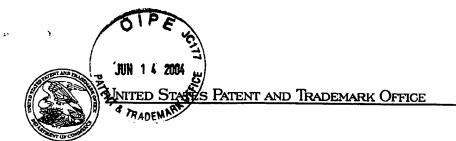
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UNITED STATES DEPARTMENT OF COMMERCE UNITED STATES DEFARIMENT OF COMMIN United States Patent and Trademark Office Address COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Vinginia 22313-1450 www.uspio.gov

APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY.DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/773,244	02/09/2004	1763	770	T2171.0214	6	4	2

CONFIRMATION NO. 7164

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32172 DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP 1177 AVENUE OF THE AMERICAS (6TH AVENUE) 41 ST FL. NEW YORK, NY 10036-2714

Applicant(s)

Date Mailed: 05/10/2004

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Tomoyasu Aoshima, Hamakita-shi, JAPAN;	THE CEIVE [N]
Domestic Priority data as claimed by applicant	MAY 1 3 2004
Foreign Applications JAPAN 2003-032196 40/02/2003 02 10	03 FINSHAPAC
lf Required, Foreign Filing License Granted: 05/08/2004	
Projected Publication Date: 04/07/2005	
Non-Publication Request: No	DSMO FILE NO. 2171.0214
Early Publication Request: No	DUE:
Title Anisotropic wet etching of silicon	C/L: ENTERED BY: ATTY: /LS
Preliminary Class	ALLY://LSS

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日本国特許庁 JAPAN PATENT OFFICE

別紙添付の書類に記載されている事項は下記の出願書類に記載されている事項と同一であることを証明する。

This is to certify that the annexed is a true copy of the following application as filed with this Office.

出願年月日 Date of Application:

2003年 2月10日

出 願 番 号 Application Number:

特願2003-032196

[ST. 10/C]:

[JP2003-032196]

期 人 pplicant(s):

ヤマハ株式会社

特許庁長官 Commissioner, Japan Patent Office 2003年 9月25日

今井康

